NL17SH125

Non-Inverting 3-State Buffer

The NL17SH125 MiniGate $^{\text{TM}}$ is an advanced high-speed CMOS non-inverting buffer in ultra-small footprint.

The NL17SH125 requires the 3-state control input (\overline{OE}) to be set High to place the output in the high impedance state.

The NL17SH125 input structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

Features

- High Speed: $t_{PD} = 3.8 \text{ ns}$ (Typ) at $V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 1.0 \mu A$ (Max) at $T_A = 25^{\circ}C$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- These are Pb-Free and Halide-Free Devices

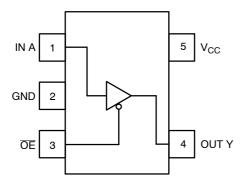


Figure 1. Pinout (Top View)



1

Figure 2. Logic Symbol



ON Semiconductor®

http://onsemi.com

MARKING DIAGRAM



SOT-953 CASE 527AE



 = Specific Device Code (Rotated 90°)

M = Month Code

| PIN ASSIGNMENT | | | | | | |
|----------------|-----------------|--|--|--|--|--|
| 1 | IN A | | | | | |
| 2 | GND | | | | | |
| 3 | ŌE | | | | | |
| 4 | OUT Y | | | | | |
| 5 | V _{CC} | | | | | |

FUNCTION TABLE

| Input A | Input OE | Output Y |
|---------|----------|----------|
| L, | L | L |
| Н | L | Н |
| Х | Н | Z |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

NL17SH125

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|----------------------|--|-------------------------------|------|
| V _{CC} | DC Supply Voltage | -0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage | -0.5 to +7.0 | V |
| V _{OUT} | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current V _{IN} < GNI | -20 | mA |
| I _{OK} | DC Output Diode Current $V_{OUT} < GND, V_{OUT} > V_{C}$ | ±20 | mA |
| I _{OUT} | DC Output Source/Sink Current | ±12.5 | mA |
| I _{CC} | DC Supply Current per Supply Pin | ±25 | mA |
| I _{GND} | DC Ground Current per Ground Pin | ±25 | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C |
| TL | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | °C |
| TJ | Junction Temperature Under Bias | +150 | °C |
| MSL | Moisture Sensitivity | Level 1 | |
| F _R | Flammability Rating Oxygen Index: 28 to 3 | 4 UL 94 V-0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage Human Body Model (Note 2 Machine Model (Note 3 Charged Device Model (Note 4 | >150 | V |
| I _{LATCHUP} | Latchup Performance Above V _{CC} and Below GND at 125°C (Note 5 | ±100 | mA |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

- Tested to EIA/JESD22-A114-A.
 Tested to EIA/JESD22-A115-A.
- Tested to JESD22-C101-A.
 Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Characteristics | | | Max | Unit |
|------------------|--|------------------------|--------|-----------|------|
| V _{CC} | Positive DC Supply Voltage | | 1.65 | 5.5 | V |
| V_{IN} | Digital Input Voltage | | 0.0 | 5.5 | V |
| V _{OUT} | Output Voltage | | 0.0 | V_{CC} | V |
| T _A | Operating Temperature Range | | -55 | +125 | °C |
| Δt / ΔV | Input Transition Rise or Fail Rate $V_{CC} = 3.3 \ V_{CC} = 5.0 \$ | / ± 0.3 V / ± 0.5 V | 0 0 | 100 20 | ns/V |

NL17SH125

DC ELECTRICAL CHARACTERISTICS

| | | | V _{CC} | 7 | Γ _A = 25° | С | T _A ≤ | 85°C | -55°C | to 125°C | |
|-----------------|------------------------------|--|-------------------|---------------------------|----------------------|---------------------------|---------------------------|---------------------------|-------------------|---------------------------|------|
| Symbol | Parameter | Test Conditions | (V) | Min | Тур | Max | Min | Max | Min | Max | Unit |
| V _{IH} | High-Level Input Voltage | | 1.65 to 2.0 | 0.75 x V _{CC} | | | 0.75 x V _{CC} | | | | ٧ |
| | | | 2.3 to 5.5 | 0.70 x V _{CC} | | | 0.70 x V _{CC} | | | | |
| V _{IL} | Low-Level Input Voltage | | 1.65 to 2.0 | | | 0.25 x V _{CC} | | 0.25 x V _{CC} | | 0.25 x V _{CC} | ٧ |
| | | | 2.3 to 5.5 | | | 0.30 x V _{CC} | | 0.30 x V _{CC} | | 0.30 x V _{CC} | |
| V _{OH} | High-Level Output Voltage | $V_{IN} = V_{IH}$ or V_{IL} $I_{OH} = -50 \mu A$ | 2.0 3.0 4.5 | 1.9 2.9 4.4 | 2.0 3.0 4.5 | | 1.9 2.9 4.4 | | 1.9 2.9 4.4 | | ٧ |
| | | $V_{IN} = V_{IH}$ or V_{IL} $I_{OH} = -4$ mA $I_{OH} = -8$ mA | 3.0 4.5 | 2.58 3.94 | | | 2.48 3.80 | | 2.34 3.66 | | |
| V _{OL} | Low-Level Output Voltage | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu\text{A}$ | 2.0 3.0 4.5 | | 0.0 0.0 0.0 | 0.1 0.1 0.1 | | 0.1 0.1 0.1 | | 0.1 0.1 0.1 | V |
| | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$ | 3.0 4.5 | | | 0.36 0.36 | | 0.44 0.44 | | 0.52 0.52 | |
| I _{IN} | Input Leakage Current | $0 \le V_{IN} \le 5.5 \text{ V}$ | 0 to 5.5 | | | ±0.1 | | ±1.0 | | ±1.0 | μΑ |
| I _{CC} | Quiescent Supply Current | $0 \le V_{IN} \le V_{CC}$ | 5.5 | | | 1.0 | | 10 | | 40 | μΑ |
| l _{OZ} | 3-State Leakage Current | $V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND | 0.0 | | | ±0.25 | | ± 2.5 | | ±2.5 | μΑ |

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

| | | V _{CC} | Test | T | T _A = 25°C |) | T _A ≤ | 85°C | −55°C t | o 125°C | |
|--|---|-----------------|--|-----|-----------------------|-------------|------------------|--------------|---------|--------------|------|
| Symbol | Parameter | (V) | Conditions | Min | Тур | Max | Min | Max | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Propagation Delay, A to Y | 3.0 to 3.6 | C _L = 15 pF C _L = 50 pF | | 5.6 8.1 | 8.0 11.5 | 1.0 1.0 | 9.5 13.0 | | 12.0 16.0 | ns |
| | | 4.5 to 5.5 | C _L = 15 pF C _L = 50 pF | | 3.8 5.3 | 5.5 7.5 | 1.0 1.0 | 6.5 8.5 | | 8.5 10.5 | |
| t _{PZL} , t _{PZH} | Output Enable Time, OE to Y | 3.0 to 3.6 | C _L = 15 pF C _L = 50 pF | | 5.4 7.9 | 8.0 11.5 | 1.0 1.0 | 9.5 13.0 | | 11.5 15.0 | ns |
| | | 4.5 to 5.5 | C _L = 15 pF C _L = 50 pF | | 3.6 5.1 | 5.1 7.1 | 1.0 1.0 | 6.0 8.0 | | 7.5 9.5 | |
| t _{PLZ} , t _{PHZ} | Output Enable Time, OE to Y | 3.0 to 3.6 | C _L = 15 pF C _L = 50 pF | | 6.5 8.0 | 9.7 13.2 | 1.0 1.0 | 11.5 15.0 | | 14.5 18.5 | ns |
| | | 4.5 to 5.5 | C _L = 15 pF C _L = 50 pF | | 4.8 7.0 | 6.8 8.8 | 1.0 1.0 | 8.0 10 | | 10.0 12.0 | |
| C _{IN} | Input Capacitance | | | | 5.5 | 10 | | 10 | | 10 | pF |
| C _{PD} | Power Dissipation Capacitance (Note 6) | 5.0 | | | 11 | | | | | | pF |

^{6.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|----------------------|-----------------------|
| NL17SH125P5T5G | SOT-953 (Pb-Free) | 8000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

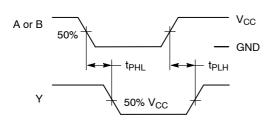


Figure 3. Switching Waveform

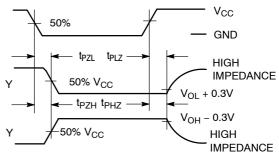
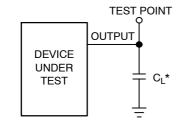


Figure 4.



*Includes all probe and jig capacitance.

 $\begin{array}{c|c} & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & &$

*Includes all probe and jig capacitance.

Figure 5. Test Circuit

Figure 6. Test Circuit

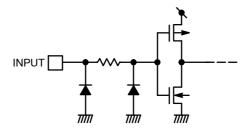


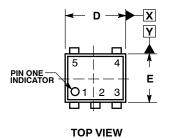
Figure 7. Input Equivalent Circuit

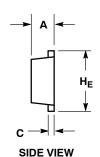


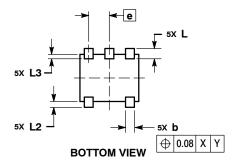
SOT-953 CASE 527AE **ISSUE E**

DATE 02 AUG 2011

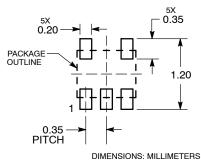








SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE
- MINIMUM THICKNESS OF THE BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
 FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | | | | | | |
|-----|-------------|----------------|------|--|--|--|--|--|
| DIM | MIN NOM MAX | | | | | | | |
| Α | 0.34 | 0.37 | 0.40 | | | | | |
| b | 0.10 | 0.10 0.15 0.20 | | | | | | |
| С | 0.07 | 0.07 0.12 0.17 | | | | | | |
| D | 0.95 | 1.00 | 1.05 | | | | | |
| E | 0.75 | 0.80 | 0.85 | | | | | |
| е | | 0.35 BS | С | | | | | |
| HE | 0.95 | 1.00 | 1.05 | | | | | |
| L | (| 0.175 RE | F | | | | | |
| L2 | 0.05 | 0.10 | 0.15 | | | | | |
| L3 | | | 0.15 | | | | | |

GENERIC MARKING DIAGRAM*



= Specific Device Code = Month Code

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| DOCUMENT NUMBER: | 98AON26457D | Electronic versions are uncontrolled except when accessed directly from the Document Repositor, Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | | | | |
|------------------|-------------|--|-------------|--|--|--|
| DESCRIPTION: | SOT-953 | | PAGE 1 OF 1 | | | |

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative